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APPLICATION NO.	E	TLING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/633,525 08/05/2003		Kuo-Chien Wu	WUKU3006/EM	5402		
23364	7590	03/04/2005		EXAMINER		
BACON &		•	GOUDREAU, GEORGE A			
625 SLATE FOURTH F				ART UNIT PAPER NUMBER		
ALEXAND	ALEXANDRIA, VA 22314			1763		
				DATE MAIL CD. 02/04/2004	•	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)	
	10/633,525	WU, KUO-CHIEN	
Office Action Summary	Examiner	Art Unit	
	George A. Goudreau	1763	
The MAILING DATE of this communication ap Period for Reply	pears on the cover sheet wi	th the correspondence add	dress
A SHORTENED STATUTORY PERIOD FOR REPL THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1, after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a replif NO period for reply specified above, the maximum statutory period. - Failure to reply within the set or extended period for reply will, by statut Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	136(a). In no event, however, may a re ply within the statutory minimum of thirt I will apply and will expire SIX (6) MON te, cause the application to become AB	ply be timely filed (30) days will be considered timely (HS from the mailing date of this co ANDONED (35 U.S.C. § 133).	
Status			
1)⊠ Responsive to communication(s) filed on 05 A	August 2003		
	is action is non-final.		
3) Since this application is in condition for allowa		ers, prosecution as to the	merits is
closed in accordance with the practice under		•	
Disposition of Claims			
4) Claim(s) 1-9 is/are pending in the application. 4a) Of the above claim(s) is/are withdra 5) Claim(s) is/are allowed. 6) Claim(s) 1-9 is/are rejected. 7) Claim(s) is/are objected to. 8) Claim(s) are subject to restriction and/o	awn from consideration.		
Application Papers			
9)☐ The specification is objected to by the Examin	er.		
10)☐ The drawing(s) filed on is/are: a)☐ acc	cepted or b) objected to t	y the Examiner.	
Applicant may not request that any objection to the	e drawing(s) be held in abeyan	ce. See 37 CFR 1.85(a).	
Replacement drawing sheet(s) including the correct	,	•	` '
11)☐ The oath or declaration is objected to by the E	xaminer. Note the attached	Office Action or form PT	O-152.
Priority under 35 U.S.C. § 119			
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority document 2. Certified copies of the priority document 3. Copies of the certified copies of the priority document application from the International Bureat * See the effected detailed Office action for a light	nts have been received. Its have been received in Aporty documents have been au (PCT Rule 17.2(a)).	oplication No received in this National \$	Stage
* See the attached detailed Office action for a list	t of the certified copies not i	GEORGE GEORGE PRIMARY	ACKULTE BOUDREAU EXAMINER
Attachment(s) 1) X Notice of References Cited (PTO-892)	4) Interview S	ummary (PTO-413)	5-05/
	7/ L IIILGI VIGW 3		l l
2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08	Paper No(s	/Mail Date formal Patent Application (PTO	

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1. Claims 1-9 are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

- -The usage of the term "unnecessary portions" in claims 1-2 is vague, and indefinite. (i.e.-What constitutes being an unnecessary portions?); and -The body of claim 1 is not commensurate in scope with the preamble of the claim 1. (i.e.-There is no steps recited in the body of claim 1 for fabricating a DRAM structure as is claimed in the preamble of claim 1.)
- 2. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless - `

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.
- 3. Claims 1-2, and 7 are rejected under 35 U.S.C. 102(b) as being anticipated by Lien (6,124,165).

Lien discloses a process for fabricating DRAM equipped with a fuse, which is comprised of the following steps:

- -An insulating layer (12) is formed onto the surface of a substrate (10).;
- -Fuses (14) are formed onto the surface of the insulating layer (12).;

-A stack of insulating layers (16, 22) is formed onto the surface of the fuses (14), and onto the surface of the insulating layer (12).;

- -A fuse window trench (2) is formed in the stack of insulating layers (16, 22) to expose the surface of the fuse (14).; and
- -A metal layer (24') is conformably formed onto the surface of the substrate. The metal layer is selectively removed from the top surface of the stack of insulating layers (16, 22).

This is shown in figure 1 specifically; and shown in general in figures 1-7. This is discussed specifically in columns 1-4; and discussed in general in columns 1-12.

4. Claims 7-8 are rejected under 35 U.S.C. 102(e) as being anticipated by Hsu (6,589,712).

Hsu discloses a device, which is formed by a process different than that which is claimed by the applicant but meets all of applicant's claimed limitations as recited in applicant's device claims. The device is comprised of a polysi fuse (37), which lies inside a fuse window (35) formed inside an insulating layer (33) on top of the surface of a Si substrate. A stack of layers (39, 49, 53) lays on the insulating layer (33) adjacent the fuse window (35). Layer 39 is comprised of SiO2. Layer 49 is comprised of SiO2 or Si3N4. Layer 53 is comprised of polyimide. There are sidewall spacers (55), which are made out of SiO2 or Si3N4 on the sidewalls of the fuse (37). This is discussed specifically in columns 2-3; and discussed in general in columns 1-6. This is shown specifically in figure 2 C; and shown in general in figures 1-3.

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5. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

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6. Any inquiry concerning this communication should be directed to examiner

George A. Goudreau at telephone number (571)-272-1434.

George A. Goudreau

Primary Examiner

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